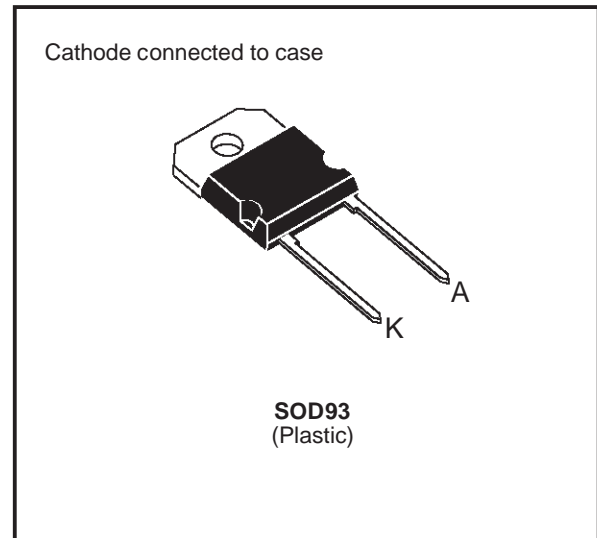




## FAST RECOVERY RECTIFIER DIODES

- VERY LOW REVERSE RECOVERY TIME
- VERY LOW SWITCHING LOSSES
- LOW NOISE TURN-OFF SWITCHING



### SUITABLE APPLICATIONS:

- FREE WHEELING DIODE IN CONVERTERS AND MOTOR CONTROL CIRCUITS
- RECTIFIER IN S.M.P.S.

### ABSOLUTE RATINGS (limiting values)

Symbol	Parameter		Value	Unit
$I_{FRM}$	Repetitive Peak Forward Current	$t_p \leq 10\mu s$	800	A
$I_{F(RMS)}$	RMS Forward Current		100	A
$I_{F(AV)}$	Average Forward Current	$T_c = 70^\circ C$ $\delta = 0.5$	60	A
$I_{FSM}$	Surge non Repetitive Forward Current	$t_p = 10ms$ Sinusoidal	550	A
P	Power Dissipation	$T_c = 70^\circ C$	100	W
$T_{stg}$ $T_j$	Storage and Junction Temperature Range		- 40 to + 150 - 40 to + 150	$^\circ C$

Symbol	Parameter	Value	Unit
$V_{RRM}$	Repetitive Peak Reverse Voltage	400	V
$V_{RSM}$	Non Repetitive Peak Reverse Voltage	440	V

### THERMAL RESISTANCE

Symbol	Parameter	Value	Unit
$R_{th(j-c)}$	Junction-case	0.8	$^\circ C/W$

# BYT 60P-400

## ELECTRICAL CHARACTERISTICS

### STATIC CHARACTERISTICS

Symbol	Test Conditions		Min.	Typ.	Max.	Unit
$I_R$	$T_j = 25^\circ\text{C}$	$V_R = V_{RRM}$			60	$\mu\text{A}$
	$T_j = 100^\circ\text{C}$				10	$\text{mA}$
$V_F$	$T_j = 25^\circ\text{C}$	$I_F = 60\text{A}$			1.5	$\text{V}$
	$T_j = 100^\circ\text{C}$				1.4	

### RECOVERY CHARACTERISTICS

Symbol	Test Conditions			Min.	Typ.	Max.	Unit
$t_{rr}$	$T_j = 25^\circ\text{C}$	$I_F = 1\text{A}$	$di_F/dt = -15\text{A}/\mu\text{s}$	$V_R = 30\text{V}$		100	$\text{ns}$
		$I_F = 0.5\text{A}$	$I_R = 1\text{A}$	$I_{rr} = 0.25\text{A}$		50	

### TURN-OFF SWITCHING CHARACTERISTICS (Without Series Inductance)

Symbol	Test Conditions		Min.	Typ.	Max.	Unit
$t_{RM}$	$di_F/dt = -240\text{A}/\mu\text{s}$	$V_{CC} = 200\text{V}$ $I_F = 60\text{A}$ $L_p \leq 0.05\mu\text{H}$ $T_j = 100^\circ\text{C}$ See Figure 11			75	$\text{ns}$
	$di_F/dt = -480\text{A}/\mu\text{s}$			50		
$I_{RM}$	$di_F/dt = -240\text{A}/\mu\text{s}$				18	$\text{A}$
	$di_F/dt = -480\text{A}/\mu\text{s}$			24		

### TURN-OFF OVERVOLTAGE COEFFICIENT - (With Series Inductance)

Symbol	Test Conditions			Min.	Typ.	Max.	Unit
$C = \frac{V_{RP}}{V_{CC}}$	$T_j = 100^\circ\text{C}$	$V_{CC} = 120\text{V}$	$I_F = I_{F(AV)}$ See note		3.3		
	$di_F/dt = -60\text{A}/\mu\text{s}$	$L_p = 1.3\mu\text{H}$	See figure 12				

Note: Applicable to BYT 60P-400 only

To evaluate the conduction losses use the following equations:

$$V_F = 1.1 + 0.0045 I_F \quad P = 1.1 \times I_{F(AV)} + 0.0045 I_F^2(\text{RMS})$$

Figure 1. Low frequency power losses versus average current.

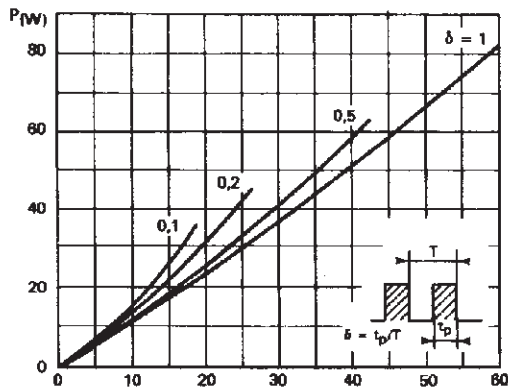


Figure 2. Peak current versus form factor.

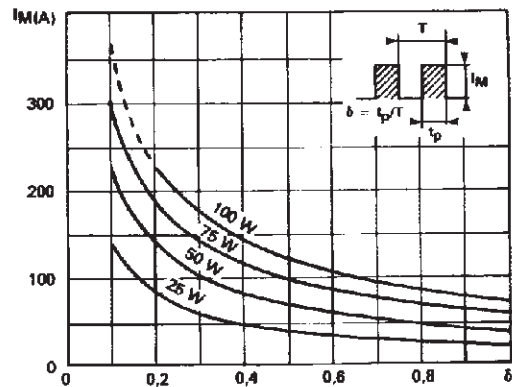


Figure 3. Non repetitive peak surge current versus overload duration

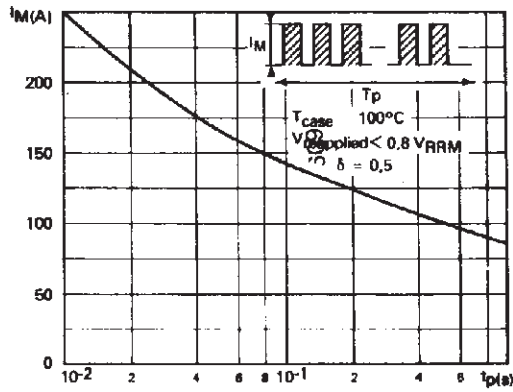


Figure 4. Thermal impedance versus pulse width.

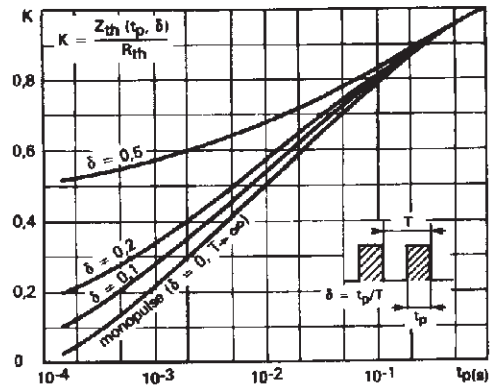


Figure 5. Voltage drop versus forward current.

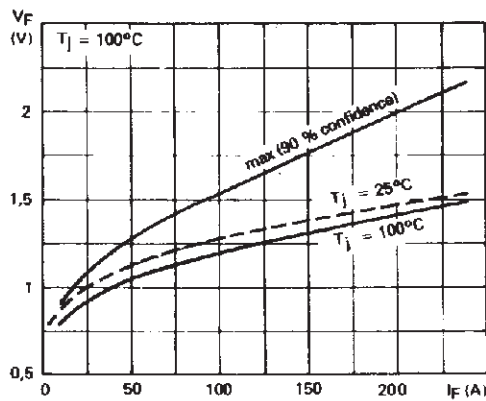


Figure 6. Recovery charge versus di\_F/dt.

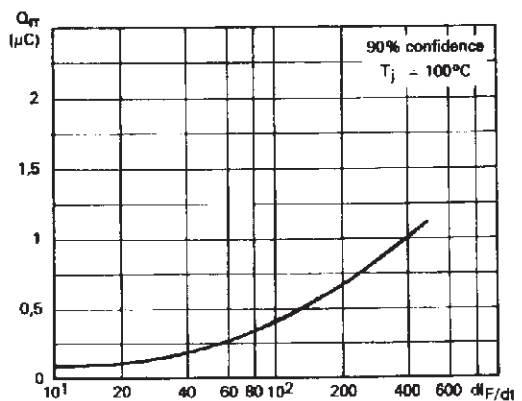


Figure 7. Recovery time versus di\_F/dt.

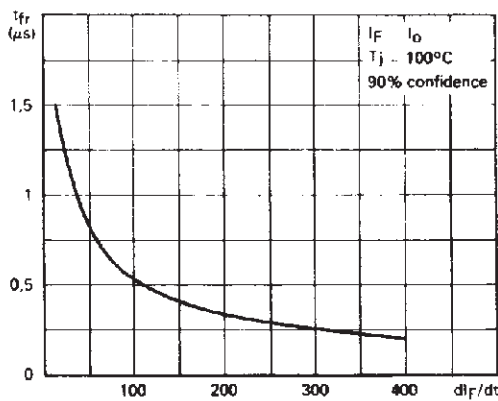
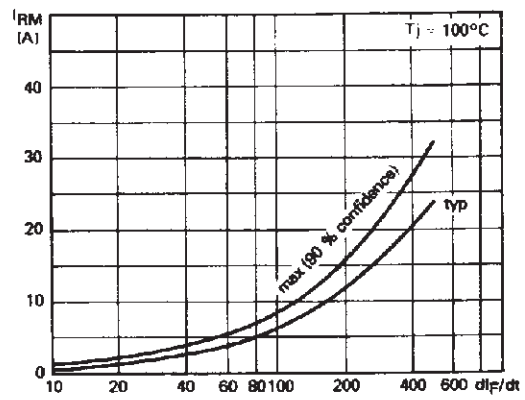


Figure 8. Peak reverse current versus di\_F/dt.



BYT 60P-400

Figure 9. Peak forward voltage versus  $di_F/dt$ .

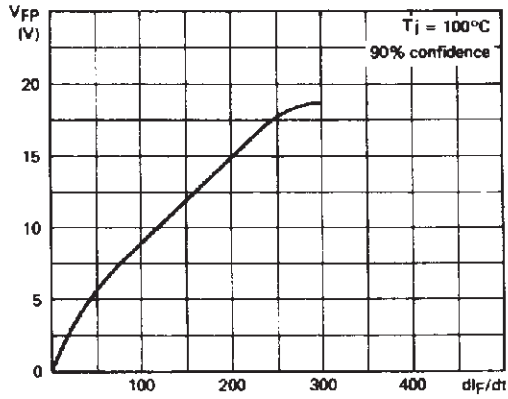


Figure 10. Dynamic parameters versus junction temperature.

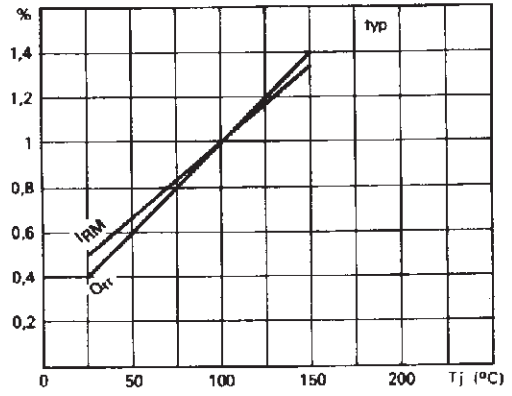


Figure 11. Turn-off switching characteristics (without series inductance).

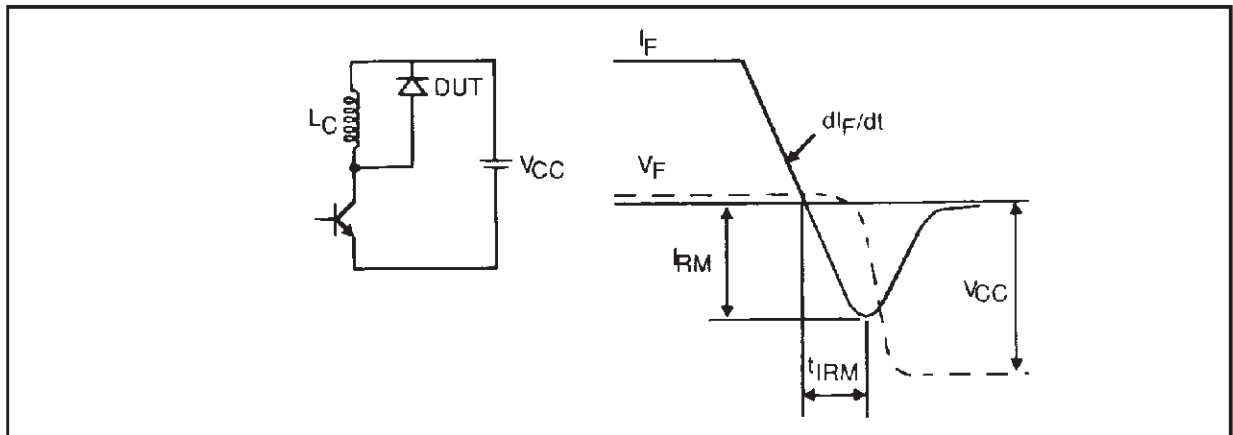
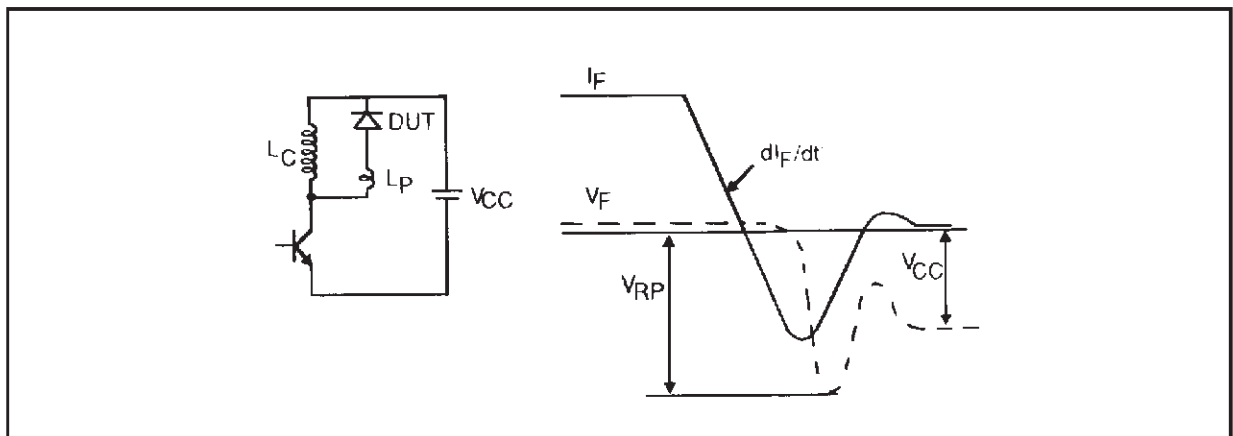
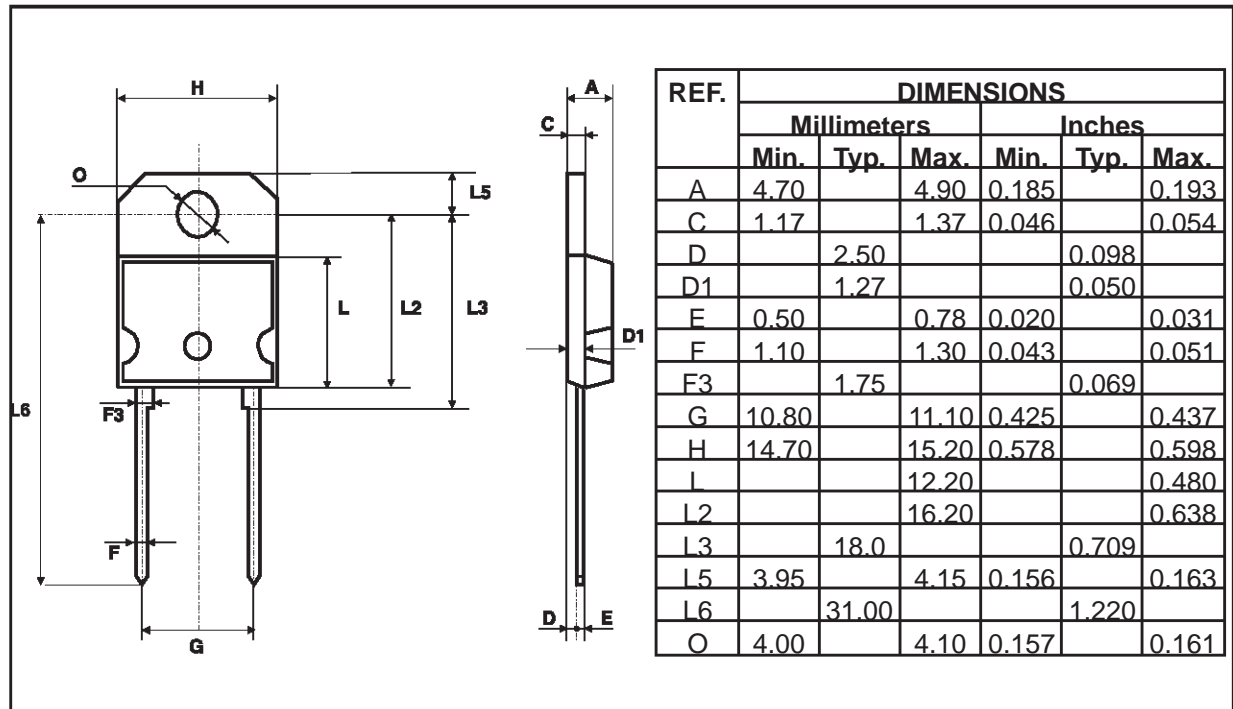


Figure 12. Turn-off switching characteristics (with series inductance).



**PACKAGE MECHANICAL DATA**  
SOD93 Plastic



- **Marking:** type number
- Cooling method: by conduction (method C)
- Weight : 3.79g
- Recommended torque value: 80cm. N
- Maximum torque value: 100cm. N

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